

### Features

- High density cell design for ultra low  $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high  $E_{AS}$
- Excellent package for good heat dissipation

### Application

- Power switching application

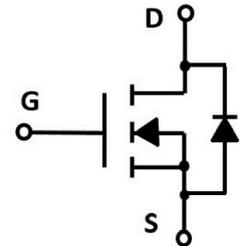
### Product Summary

| $V_{DS}$ | $R_{DS(ON)}$ MAX | $I_D$ MAX |
|----------|------------------|-----------|
| 150V     | 70mΩ@10V         | 30A       |



Marking and pin assignment

MU1F30A : Device code  
 XXXX : Code



Schematic diagram



Halogen-Free

### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol   | Parameter                           | Rating                        | Unit |
|--|-------------------------------------|-------------------------------|------|
| <b>Common Ratings (TC=25°C Unless Otherwise Noted)</b> |                                     |                               |      |
| $V_{DS}$   | Drain-Source Breakdown Voltage      | 150                           | V    |
| $V_{GS}$   | Gate-Source Voltage                 | ±20                           | V    |
| $T_J$  | Maximum Junction Temperature        | 150                           | °C   |
| $T_{STG}$  | Storage Temperature Range           | -50 to 155                    | °C   |
| $I_S$  | Diode Continuous Forward Current    | $T_C=25^\circ\text{C}$<br>30  | A    |
| <b>Mounted on Large Heat Sink</b>                      |                                     |                               |      |
| $I_{DM}$   | Pulse Drain Current Tested          | $T_C=25^\circ\text{C}$<br>120 | A    |
| $I_D$  | Continuous Drain Current            | $T_C=25^\circ\text{C}$<br>30  | A    |
| $P_D$  | Maximum Power Dissipation           | $T_C=25^\circ\text{C}$<br>83  | W    |
| $R_{\theta JA}$  | Thermal Resistance Junction-Ambient | 45                            | °C/W |

### Ordering Information (Example)

| Type    | Package | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|---------|---------|---------|----------------------|-------------------------|----------------------------|---------------|
| MU1F30A | TO-252  | MU1F30A | 2,500                | 5,000                   | 35,000                     | 13"reel       |

| Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)                   |                                  |  |     |     |      |      |
|--|----------------------------------|--|-----|-----|------|------|
| Symbol   | Parameter                        | Condition  | Min | Typ | Max  | Unit |
| <b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>  |                                  |  |     |     |      |      |
| BV <sub>(BR)DSS</sub>  | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA   | 150 | --  | --   | V    |
| I <sub>DSS</sub>   | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =150V, V <sub>GS</sub> =0V   | --  | --  | 1    | μA   |
| I <sub>GSS</sub>   | Gate-Body Leakage Current        | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V   | --  | --  | ±100 | nA   |
| V <sub>GS(th)</sub>  | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                 | 2   | --  | 4    | V    |
| R <sub>DS(on)</sub>  | Drain-Source On-State Resistance | V <sub>GS</sub> =10V, I <sub>D</sub> =20A  | --  | 50  | 70   | mΩ   |
| <b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b> |                                  |  |     |     |      |      |
| C <sub>ISS</sub>   | Input Capacitance                | V <sub>DS</sub> =75V, V <sub>GS</sub> =0V, f=1MHz  | --  | 750 | --   | pF   |
| C <sub>OSS</sub>   | Output Capacitance               |  | --  | 65  | --   | pF   |
| C <sub>RSS</sub>   | Reverse Transfer Capacitance     |  | --  | 5   | --   | pF   |
| <b>Switching Characteristics</b>   |                                  |  |     |     |      |      |
| Q <sub>g</sub>   | Total Gate Charge                | V <sub>DS</sub> =75V, I <sub>D</sub> =20A,<br>V <sub>GS</sub> =10V                       | --  | 16  | --   | nC   |
| Q <sub>gs</sub>  | Gate Source Charge               |  | --  | 3   | --   | nC   |
| Q <sub>gd</sub>  | Gate Drain Charge                |  | --  | 4   | --   | nC   |
| t <sub>d(on)</sub>   | Turn-on Delay Time               | V <sub>DD</sub> =75V, I <sub>D</sub> =20A,<br>V <sub>GS</sub> =10V, R <sub>G</sub> =2.2Ω | --  | 7   | --   | nS   |
| t <sub>r</sub>   | Turn-on Rise Time                |  | --  | 20  | --   | nS   |
| t <sub>d(off)</sub>  | Turn-Off Delay Time              |  | --  | 16  | --   | nS   |
| t <sub>f</sub>   | Turn-Off Fall Time               |  | --  | 14  | --   | nS   |
| <b>Source- Drain Diode Characteristics</b>   |                                  |  |     |     |      |      |
| V <sub>SD</sub>  | Forward on voltage               | T <sub>J</sub> =25°C, I <sub>S</sub> =10A  | --  | --  | 1.2  | V    |

Typical Operating Characteristics

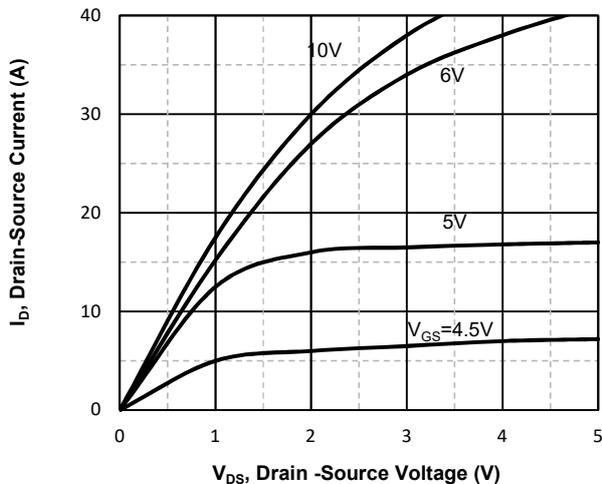


Fig1. Typical Output Characteristics

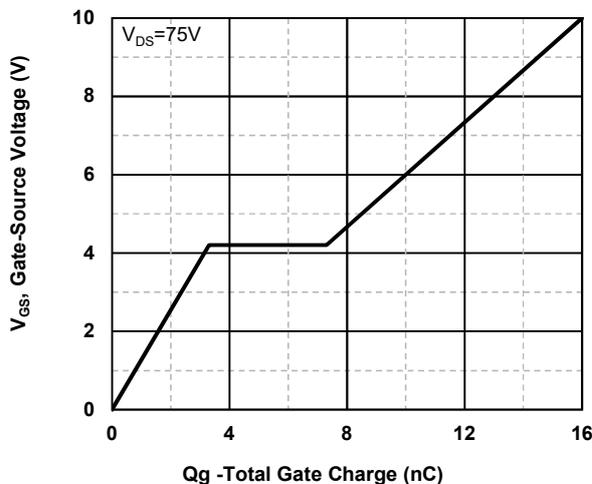


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

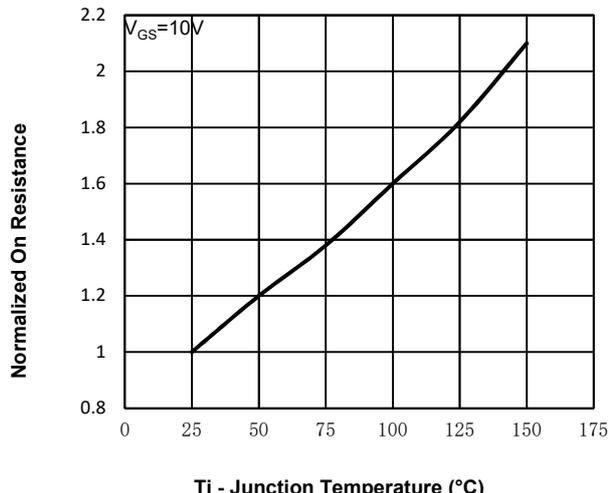


Fig3. Normalized On-Resistance Vs. Temperature

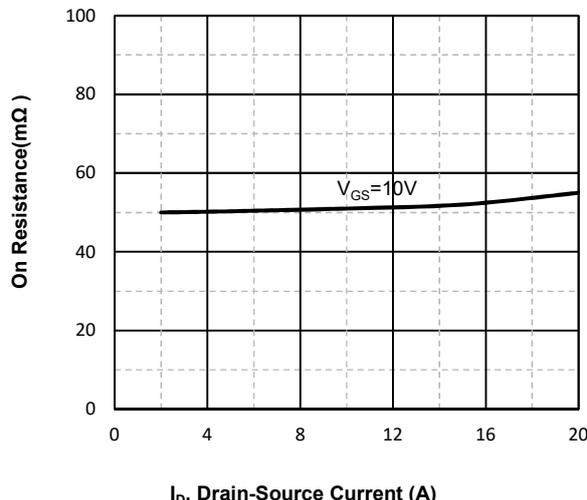


Fig4. On-Resistance Vs. Drain-Source Current

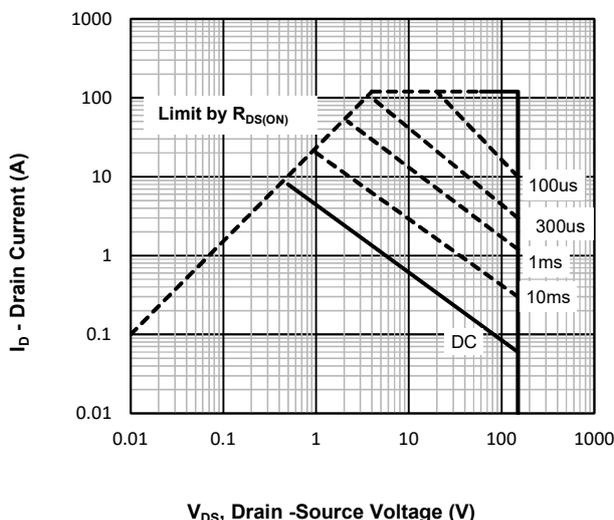


Fig5. Maximum Safe Operating Area

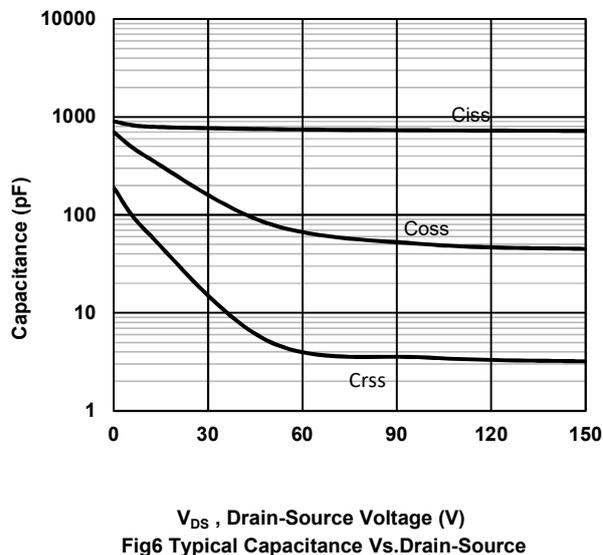
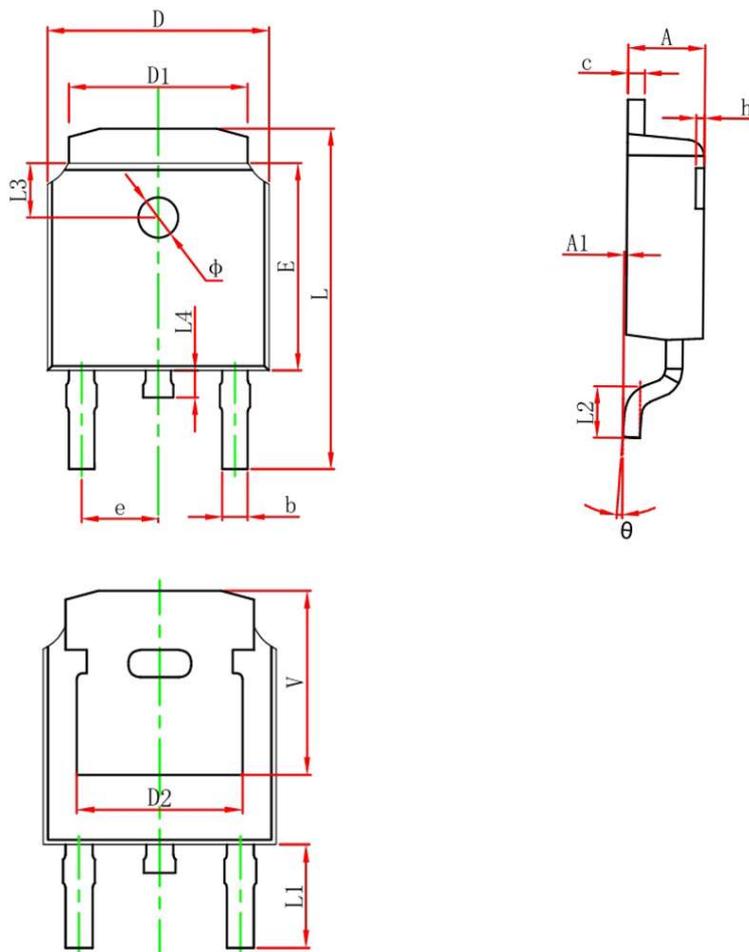


Fig6 Typical Capacitance Vs. Drain-Source

**TO-252 Package information**


| Symbol   | Dimensions in Millimeters(mm) |        | Dimensions In Inches |       |
|----------|-------------------------------|--------|----------------------|-------|
|          | Min                           | Max    | Min                  | Max   |
| A        | 2.200                         | 2.400  | 0.087                | 0.094 |
| A1       | 0.000                         | 0.127  | 0.000                | 0.005 |
| b        | 0.635                         | 0.770  | 0.025                | 0.030 |
| c        | 0.450                         | 0.580  | 0.018                | 0.023 |
| D        | 6.500                         | 6.700  | 0.256                | 0.264 |
| D1       | 5.100                         | 5.460  | 0.201                | 0.215 |
| D2       | 4.830 REF.                    |        | 0.190 REF.           |       |
| E        | 6.000                         | 6.200  | 0.236                | 0.244 |
| e        | 2.186                         | 2.386  | 0.086                | 0.094 |
| L        | 9.712                         | 10.312 | 0.386                | 0.406 |
| L1       | 2.900 REF.                    |        | 0.114 REF.           |       |
| L2       | 1.400                         | 1.700  | 0.055                | 0.067 |
| L3       | 1.600 REF.                    |        | 0.063 REF.           |       |
| L4       | 0.600                         | 1.000  | 0.024                | 0.039 |
| $\Phi$   | 1.100                         | 1.300  | 0.043                | 0.051 |
| $\theta$ | 0°                            | 8°     | 0°                   | 8°    |
| h        | 0.000                         | 0.300  | 0.000                | 0.012 |
| V        | 5.250 REF.                    |        | 0.207 REF.           |       |